



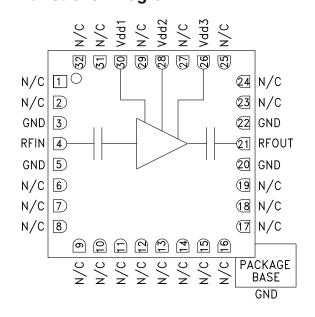
# SMT PHEMT LOW NOISE AMPLIFIER, 9 - 18 GHz

#### Typical Applications

The HMC516LC5 is ideal for use as a LNA or driver amplifier for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- Test Equipment and Sensors
- Military

# Functional Diagram



#### **Features**

Noise Figure: 2 dB

Gain: 20 dB OIP3: +25 dBm

Single Supply: +3V @ 65 mA 50 Ohm Matched Input/Output

RoHS Compliant 5x5 mm Package

### **General Description**

The HMC516LC5 is a high dynamic range GaAs pHEMT MMIC Low Noise Amplifier (LNA) housed in a leadless "Pb free" RoHS compliant SMT package. The HMC516LC5 provides 20 dB of small signal gain, 2 dB of noise figure and has an output IP3 of +25 dBm. The P1dB output power of +13 dBm enables the LNA to also function as a LO driver for balanced, I/Q or image reject mixers. The HMC516LC5 allows the use of surface mount manufacturing techniques.

### Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, Vdd 1, 2, 3 = +3V

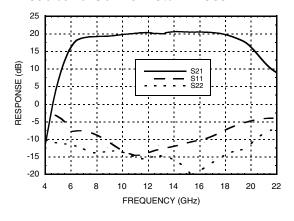
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range		9 - 12 12 - 18		GHz			
Gain	17.5	20		18	20.5		dB
Gain Variation Over Temperature		0.015	0.025		0.015	0.025	dB/ °C
Noise Figure		2.0	2.5		2.0	2.5	dB
Input Return Loss		10			10		dB
Output Return Loss		12			12		dB
Output Power for 1 dB Compression (P1dB)		13			14		dBm
Saturated Output Power (Psat)		15			16		dBm
Output Third Order Intercept (IP3)		25			25		dBm
Supply Current (ldd)(Vdd = +3V)		65	88		65	88	mA



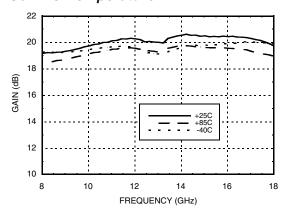


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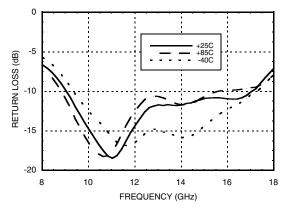
#### **Broadband Gain & Return Loss**



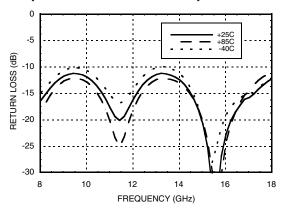
#### Gain vs. Temperature



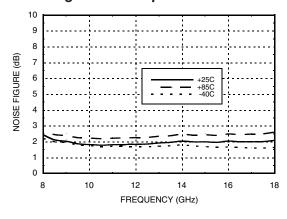
#### Input Return Loss vs. Temperature



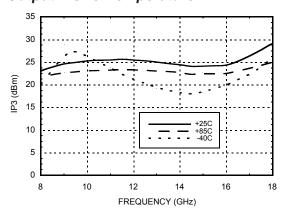
#### Output Return Loss vs. Temperature



#### Noise Figure vs. Temperature



#### Output IP3 vs. Temperature

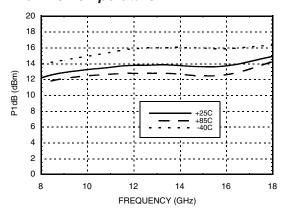


**ANALOG**DEVICES

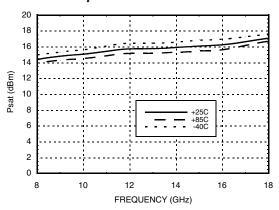


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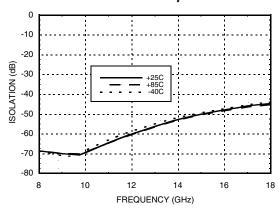
#### P1dB vs. Temperature



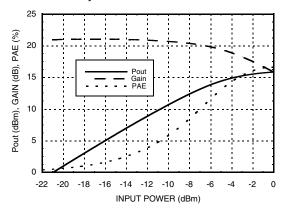
#### Psat vs. Temperature



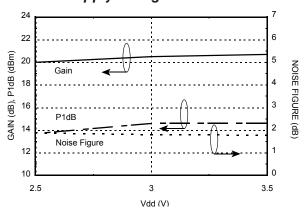
#### Reverse Isolation vs. Temperature



#### **Power Compression @ 12 GHz**



#### Gain, Noise Figure & Power vs. Supply Voltage @ 12 GHz







# SMT PHEMT LOW NOISE AMPLIFIER, 9 - 18 GHz

#### **Absolute Maximum Ratings**

Drain Bias Voltage (Vdd1, Vdd2, Vdd3)	+4 Vdc	
RF Input Power (RFIN)(Vdd = +3.0 Vdc)	+5 dBm	
Channel Temperature	175 °C	
Continuous Pdiss (T= 85 °C) (derate 14 mW/°C above 85 °C)	1.25 W	
Thermal Resistance (channel to die bottom)	71 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	
ESD Sensitivity (HBM)	Class 1A	

#### Typical Supply Current vs. Vdd

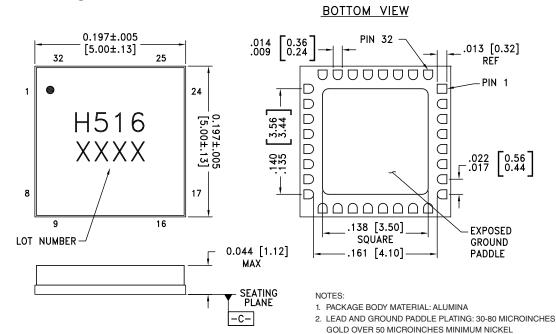
Vdd (V)	ldd (mA)		
+2.5	61		
+3.0	65		
+3.5	69		

Note: Amplifier will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

#### **Outline Drawing**



### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC516LC5	Alumina, White	Gold over Nickel	MSL3 [1]	H516 XXXX

<sup>[1]</sup> Max peak reflow temperature of 260  $^{\circ}\text{C}$ 

DIMENSIONS ARE IN INCHES [MILLIMETERS]
 LEAD SPACING TOLERANCE IS NON-CUMULATIVE
 PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM
 ALL GROUND LEADS AND GROUND PADDLE MUST BE

SOLDERED TO PCB RF GROUND

<sup>[2] 4-</sup>Digit lot number XXXX





# SMT PHEMT LOW NOISE AMPLIFIER, 9 - 18 GHz

#### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1, 2, 6 - 19, 23 - 25, 27, 29, 31, 32	N/C	This pin may be connected to RF/DC ground. Performance will not be affected.	
4	RFIN	This pin is AC coupled and matched to 50 Ohms.	RFIN ○──  ├──
30, 28, 26	Vdd1, 2, 3	Power Supply Voltage for the amplifier. External bypass capacitors of 100 pF and 2.2 μF are required.	OVdd1,2,3
21	RFOUT	This pin is AC coupled and matched to 50 Ohms.	—   —○ RFOUT
3, 5, 20, 22	GND	These pins and package bottom must be connected to RF/DC ground.	GND

### **Application Circuit**

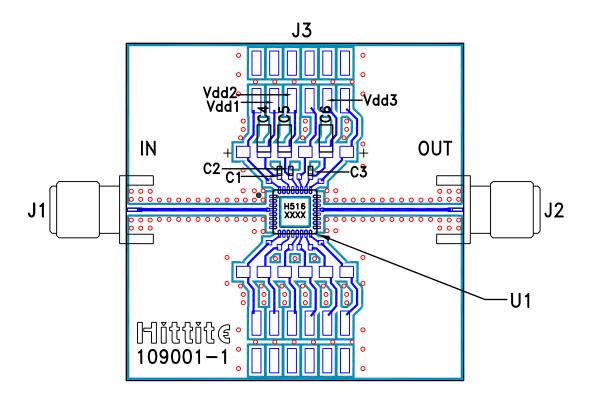
Component	Value	Vdd	1 Vdd2	Vdd3	
C1, C2, C3	100 pF	φ	φ	φ	
C4, C5, C6	2.2 μF				_
		±c1   c	$c_4 \perp \qquad \downarrow c_2 \mid c_5$		
		701	74— — 02   03	T T 03   00 -	
			$\perp$ $\perp$ $\mid$	<u> </u>	<u> </u>
		_			_
					1
		30	28	26	
	RFIN >	4		21	RFOUT





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#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 110431 [1]

Item	Description	
J1 - J2	PCB Mount K Connector	
J3	2 mm DC Header	
C1 - C3	100 pF Capacitor, 0402 Pkg.	
C4 - C6	2.2 μF Capacitor, Tantalum	
U1	HMC516LC5 Amplifier	
PCB [2] 109001 Evaluation PCB		

[1] Reference this number when ordering complete evaluation PCB  $\,$ 

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.